

# 74LVC1G99

Ultra-configurable multiple function gate; 3-state

Rev. 8 — 5 April 2013

Product data sheet

## 1. General description

The 74LVC1G99 provides a low voltage, ultra-configurable, multiple function gate with 3-state output. The device can be configured as one of several logic functions including, AND, OR, NAND, NOR, XOR, XNOR, inverter, buffer and MUX. No external components are required to configure the device as all inputs can be connected directly to  $V_{CC}$  or  $\overline{GND}$ . The 3-state output is controlled by the output enable input ( $\overline{OE}$ ). A HIGH level at  $\overline{OE}$  causes the output (Y) to assume a high-impedance OFF-state. When  $\overline{OE}$  is LOW, the output state is determined by the signals applied to the Schmitt trigger inputs (A, B, C and D).

Due to the use of Schmitt trigger inputs the device is tolerant of slowly changing input signals, transforming them into sharply defined, jitter free output signals. By eliminating leakage current paths to  $V_{CC}$  and GND, the inputs and disabled output are also over-voltage tolerant, making the device suitable for mixed-voltage applications.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The 74LVC1G99 is fully specified over the supply range from 1.65 V to 5.5 V.

## 2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant inputs for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
  - ◆ JESD8-7 (1.65 V to 1.95 V)
  - ◆ JESD8-5 (2.3 V to 2.7 V)
  - ◆ JESD8-B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
- $\pm 24$  mA output drive ( $V_{CC} = 3.0$  V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- Specified from  $-40$  °C to  $+85$  °C and  $-40$  °C to  $+125$  °C.



### 3. Ordering information

**Table 1.** Ordering information

| Type number | Package           |        |                                                                                             |          |
|-------------|-------------------|--------|---------------------------------------------------------------------------------------------|----------|
|             | Temperature range | Name   | Description                                                                                 | Version  |
| 74LVC1G99DP | –40 °C to +125 °C | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm     | SOT505-2 |
| 74LVC1G99GT | –40 °C to +125 °C | XSON8  | plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm | SOT833-1 |
| 74LVC1G99GF | –40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm         | SOT1089  |
| 74LVC1G99GD | –40 °C to +125 °C | XSON8  | plastic extremely thin small outline package; no leads; 8 terminals; body 3 × 2 × 0.5 mm    | SOT996-2 |
| 74LVC1G99GM | –40 °C to +125 °C | XQFN8  | plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 × 1.6 × 0.5 mm   | SOT902-2 |
| 74LVC1G99GN | –40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm       | SOT1116  |
| 74LVC1G99GS | –40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm      | SOT1203  |

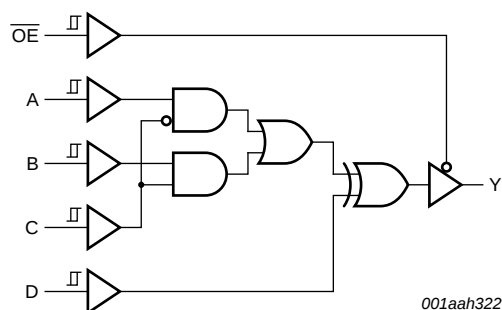
### 4. Marking

**Table 2.** Marking codes

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| 74LVC1G99DP | V99                         |
| 74LVC1G99GT | V99                         |
| 74LVC1G99GF | YF                          |
| 74LVC1G99GD | V99                         |
| 74LVC1G99GM | V99                         |
| 74LVC1G99GN | YF                          |
| 74LVC1G99GS | YF                          |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

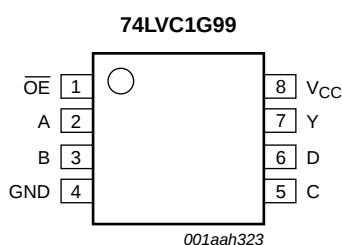
## 5. Functional diagram



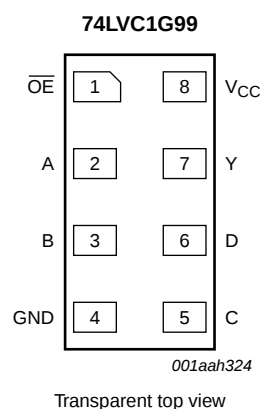
**Fig 1. Logic symbol**

## 6. Pinning information

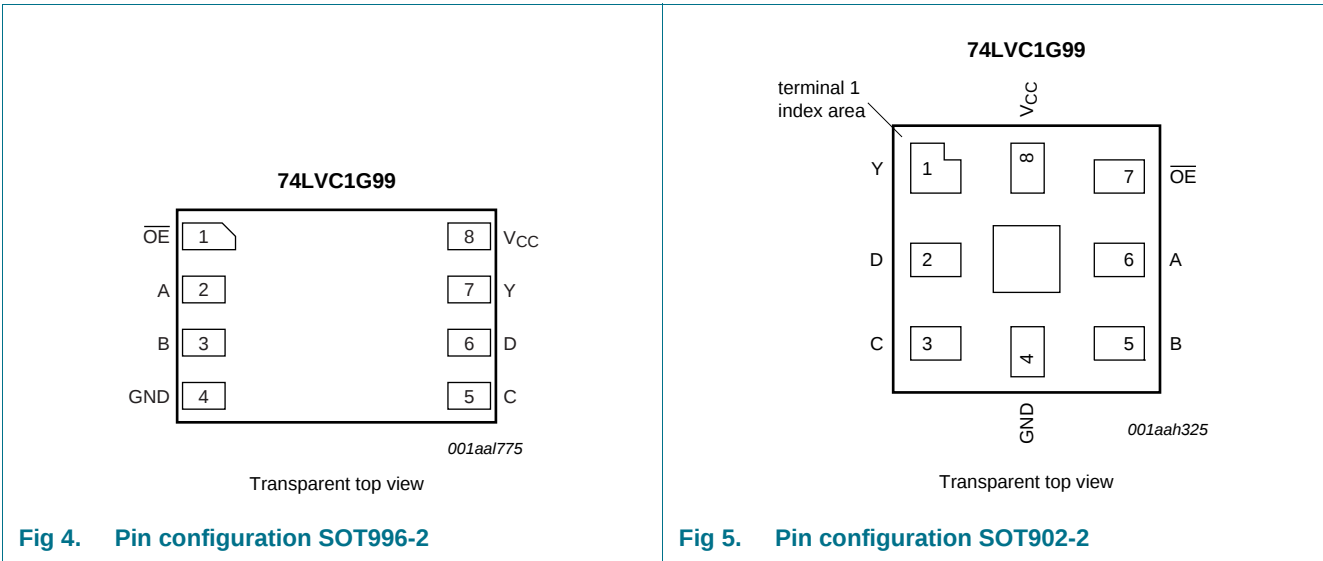
## 6.1 Pinning



**Fig 2. Pin configuration SOT505-2**



**Fig 3. Pin configuration SOT833-1, SOT1089, SOT1116 and SOT1203**



6.2 Pin description

Table 3. Pin description

| Symbol          | Pin                                                        |          | Description                                      |
|-----------------|------------------------------------------------------------|----------|--------------------------------------------------|
|                 | SOT505-2, SOT833-1, SOT1089, SOT1116, SOT1203 and SOT996-2 | SOT902-2 |                                                  |
| $\overline{OE}$ | 1                                                          | 7        | output enable input $\overline{OE}$ (active LOW) |
| A               | 2                                                          | 6        | data input                                       |
| B               | 3                                                          | 5        | data input                                       |
| GND             | 4                                                          | 4        | ground (0 V)                                     |
| C               | 5                                                          | 3        | data input                                       |
| D               | 6                                                          | 2        | data input                                       |
| Y               | 7                                                          | 1        | data output                                      |
| V <sub>CC</sub> | 8                                                          | 8        | supply voltage                                   |

## 7. Functional description

Table 4. Function table<sup>[1]</sup>

| Input |   |   |   |   | Output |
|-------|---|---|---|---|--------|
| OE    | D | C | B | A | Y      |
| L     | L | L | L | L | L      |
| L     | L | L | L | H | H      |
| L     | L | L | H | L | L      |
| L     | L | L | H | H | H      |
| L     | L | H | L | L | L      |
| L     | L | H | L | H | L      |
| L     | L | H | H | L | H      |
| L     | L | H | H | H | H      |
| L     | H | L | L | L | H      |
| L     | H | L | L | H | L      |
| L     | H | L | H | L | H      |
| L     | H | L | H | H | L      |
| L     | H | H | L | L | H      |
| L     | H | H | L | H | H      |
| L     | H | H | H | L | L      |
| L     | H | H | H | H | L      |
| H     | X | X | X | X | Z      |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7.1 Logic configurations

Table 5. Function selection table

| Primary function                                  | Complementary function                        |
|---------------------------------------------------|-----------------------------------------------|
| 3-state buffer                                    |                                               |
| 3-state inverter                                  |                                               |
| 3-state 2-input multiplexer                       |                                               |
| 3-state 2-input multiplexer with inverting output |                                               |
| 3-state 2-input AND                               | 3-state 2-input NOR with two inverting inputs |
| 3-state 2-input AND with one inverting input      | 3-state 2-input NOR with one inverting input  |
| 3-state 2-input AND with two inverting inputs     | 3-state 2-input NOR                           |
| 3-state 2-input NAND                              | 3-state 2-input OR with two inverting inputs  |
| 3-state 2-input NAND with one inverting input     | 3-state 2-input OR with one inverting input   |
| 3-state 2-input NAND with two inverting inputs    | 3-state 2-input OR                            |
| 3-state 2-input XOR                               |                                               |
| 3-state 2-input XNOR                              | 3-state 2-input XOR with one inverting input  |

7.2 3-state buffer functions available

Table 6. Function table<sup>[1]</sup>  
See [Figure 6](#).

| Function       | Input |        |        |        |       |
|----------------|-------|--------|--------|--------|-------|
|                | OE    | A      | B      | C      | D     |
| 3-state buffer | L     | input  | H or L | L      | L     |
|                | L     | H or L | input  | H      | L     |
|                | L     | L      | H      | input  | L     |
|                | L     | H      | L      | input  | H     |
|                | L     | H      | H or L | L      | input |
|                | L     | H or L | L      | H      | input |
|                | L     | L      | L      | H or L | input |

[1] H = HIGH voltage level;  
L = LOW voltage level.

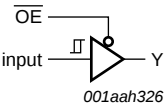


Fig 6. 3-state buffer function

7.3 3-state inverter functions available

Table 7. Function table<sup>[1]</sup>  
See [Figure 7](#).

| Function         | Input |        |        |        |       |
|------------------|-------|--------|--------|--------|-------|
|                  | OE    | A      | B      | C      | D     |
| 3-state inverter | L     | input  | H or L | L      | H     |
|                  | L     | X      | input  | H      | H     |
|                  | L     | L      | H      | input  | H     |
|                  | L     | H      | L      | input  | L     |
|                  | L     | H      | H or L | L      | input |
|                  | L     | H or L | H      | H      | input |
|                  | L     | H      | H      | H or L | input |

[1] H = HIGH voltage level;  
L = LOW voltage level.  
X = don't care.

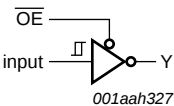


Fig 7. 3-state inverter function

7.4 3-state multiplexer functions available

Table 8. Function table<sup>[1]</sup>  
See [Figure 8](#).

| Function                    | Input |         |         |                    |   |
|-----------------------------|-------|---------|---------|--------------------|---|
|                             | OE    | A       | B       | C                  | D |
| 3-state 2-input multiplexer | L     | input 1 | input 2 | input 1 or input 2 | L |
|                             | L     | input 2 | input 1 | input 2 or input 1 | L |
|                             | L     | input 1 | input 2 | input 1 or input 2 | H |
|                             | L     | input 2 | input 1 | input 2 or input 1 | H |

[1] H = HIGH voltage level;  
L = LOW voltage level.

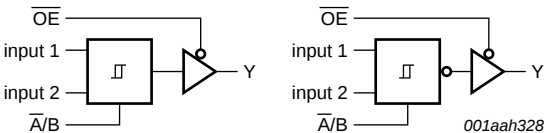


Fig 8. 3-state 2-input multiplexer function

7.5 3-state AND/NOR functions available

Table 9. Function table<sup>[1]</sup>  
See Figure 9.

| Number of inputs | Function    |             | Input                  |   |         |         |   |
|------------------|-------------|-------------|------------------------|---|---------|---------|---|
|                  | AND/NAND    | OR/NOR      | $\overline{\text{OE}}$ | A | B       | C       | D |
| 2                | 3-state AND | 3-state NOR | L                      | L | input 1 | input 2 | L |
| 2                | 3-state AND | 3-state NOR | L                      | L | input 2 | input 1 | L |

[1] H = HIGH voltage level;  
L = LOW voltage level.

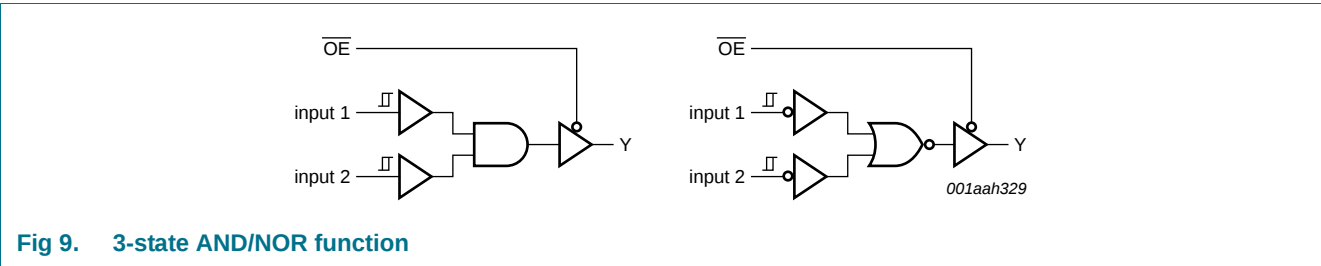


Fig 9. 3-state AND/NOR function

Table 10. Function table<sup>[1]</sup>  
See Figure 10.

| Number of inputs | Function    |             | Input                  |         |         |         |   |
|------------------|-------------|-------------|------------------------|---------|---------|---------|---|
|                  | AND/NAND    | OR/NOR      | $\overline{\text{OE}}$ | A       | B       | C       | D |
| 2                | 3-state AND | 3-state NOR | L                      | input 2 | L       | input 1 | L |
| 2                | 3-state AND | 3-state NOR | L                      | H       | input 1 | input 2 | H |

[1] H = HIGH voltage level;  
L = LOW voltage level.

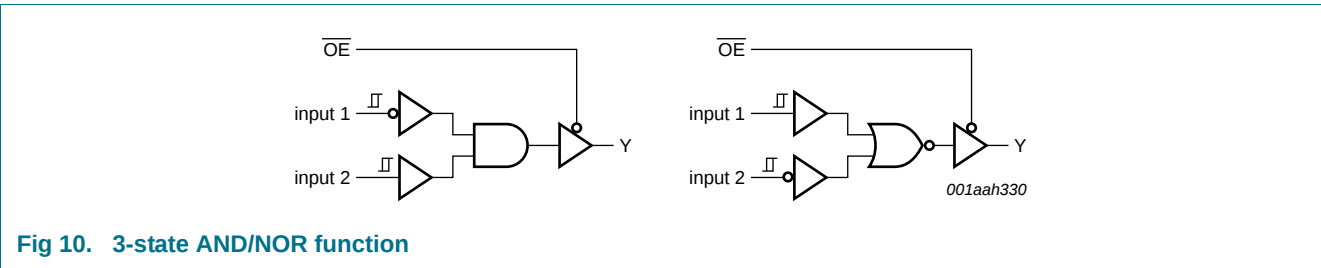
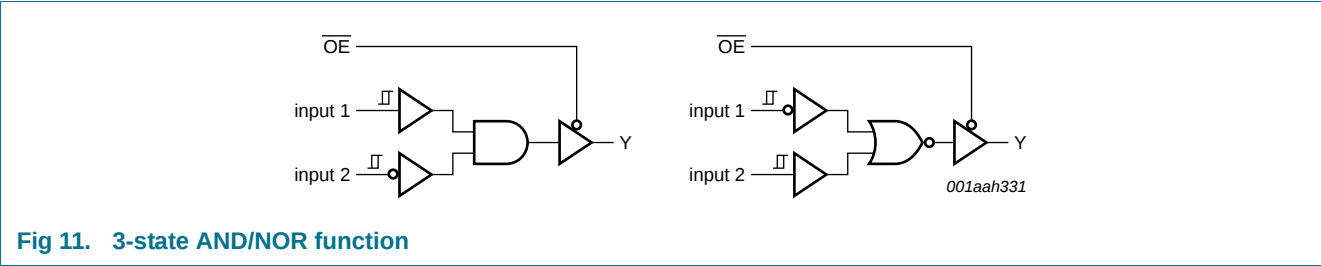


Fig 10. 3-state AND/NOR function

**Table 11. Function table**<sup>[1]</sup>  
 See [Figure 11](#).

| Number of inputs | Function    |             | Input                  |         |         |         |   |
|------------------|-------------|-------------|------------------------|---------|---------|---------|---|
|                  | AND/NAND    | OR/NOR      | $\overline{\text{OE}}$ | A       | B       | C       | D |
| 2                | 3-state AND | 3-state NOR | L                      | input 1 | L       | input 2 | L |
| 2                | 3-state AND | 3-state NOR | L                      | H       | input 2 | input 1 | H |

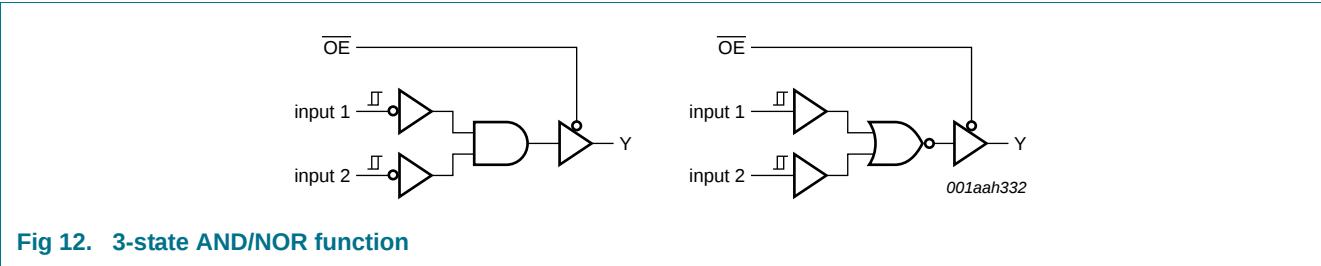
[1] H = HIGH voltage level;  
 L = LOW voltage level.



**Table 12. Function table**<sup>[1]</sup>  
 See [Figure 12](#).

| Number of inputs | Function    |             | Input                  |         |   |         |   |
|------------------|-------------|-------------|------------------------|---------|---|---------|---|
|                  | AND/NAND    | OR/NOR      | $\overline{\text{OE}}$ | A       | B | C       | D |
| 2                | 3-state AND | 3-state NOR | L                      | input 1 | H | input 2 | L |
| 2                | 3-state AND | 3-state NOR | L                      | input 2 | H | input 1 | L |

[1] H = HIGH voltage level;  
 L = LOW voltage level.



7.6 3-state NAND/OR functions available

Table 13. Function table<sup>[1]</sup>  
See Figure 13.

| Number of inputs | Function     |            | Input           |   |         |         |   |
|------------------|--------------|------------|-----------------|---|---------|---------|---|
|                  | AND/NAND     | OR/NOR     | $\overline{OE}$ | A | B       | C       | D |
| 2                | 3-state NAND | 3-state OR | L               | L | input 1 | input 2 | H |
| 2                | 3-state NAND | 3-state OR | L               | L | input 2 | input 1 | H |

[1] H = HIGH voltage level;  
L = LOW voltage level.

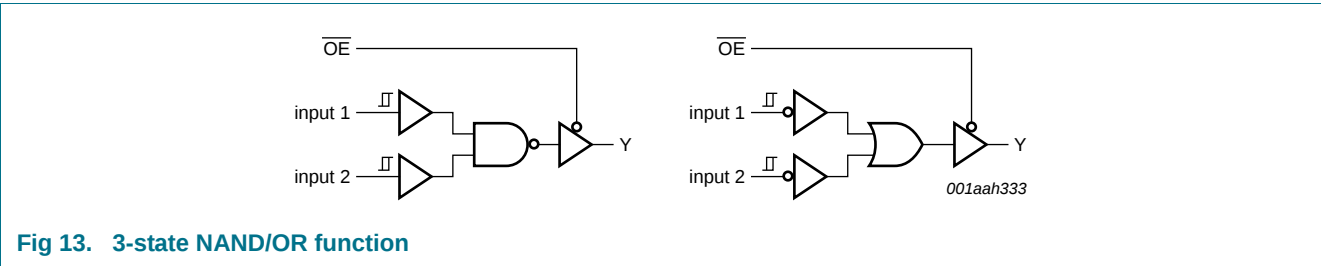


Fig 13. 3-state NAND/OR function

Table 14. Function table<sup>[1]</sup>  
See Figure 14.

| Number of inputs | Function     |            | Input           |         |         |         |   |
|------------------|--------------|------------|-----------------|---------|---------|---------|---|
|                  | AND/NAND     | OR/NOR     | $\overline{OE}$ | A       | B       | C       | D |
| 2                | 3-state NAND | 3-state OR | L               | input 2 | L       | input 1 | H |
| 2                | 3-state NAND | 3-state OR | L               | H       | input 1 | input 2 | L |

[1] H = HIGH voltage level;  
L = LOW voltage level.

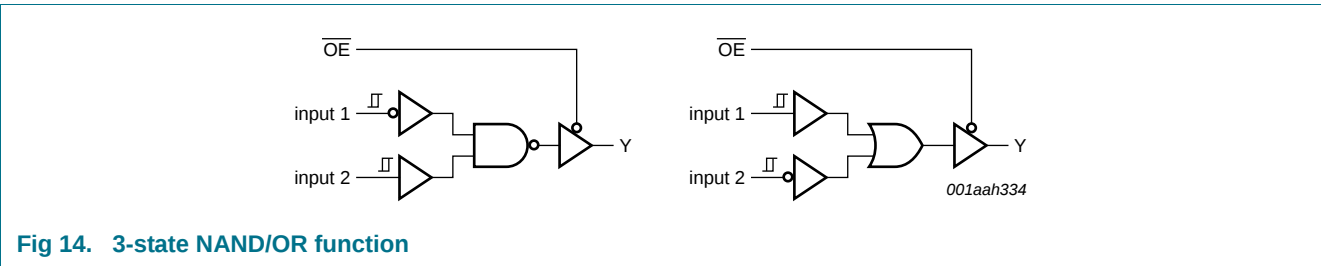


Fig 14. 3-state NAND/OR function

Table 15. Function table<sup>[1]</sup>

See [Figure 15](#).

| Number of inputs | Function     |            | Input                  |         |         |         |   |
|------------------|--------------|------------|------------------------|---------|---------|---------|---|
|                  | AND/NAND     | OR/NOR     | $\overline{\text{OE}}$ | A       | B       | C       | D |
| 2                | 3-state NAND | 3-state OR | L                      | input 1 | L       | input 2 | H |
| 2                | 3-state NAND | 3-state OR | L                      | H       | input 2 | input 1 | L |

[1] H = HIGH voltage level;  
L = LOW voltage level.

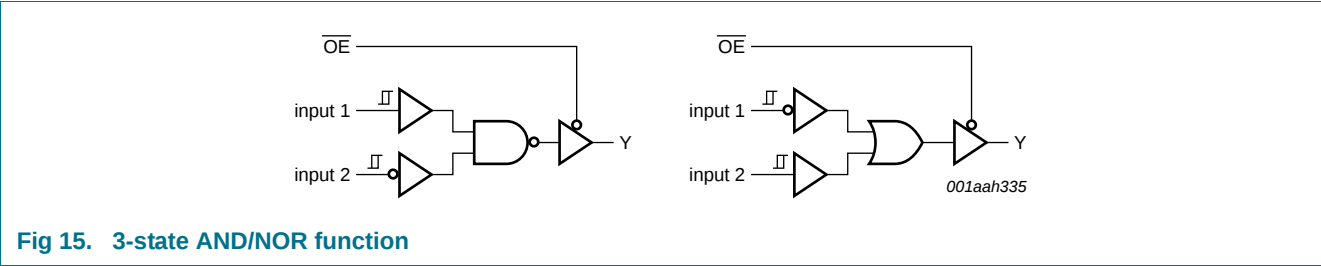


Fig 15. 3-state AND/NOR function

Table 16. Function table<sup>[1]</sup>

See [Figure 16](#).

| Number of inputs | Function     |            | Input                  |         |   |         |   |
|------------------|--------------|------------|------------------------|---------|---|---------|---|
|                  | AND/NAND     | OR/NOR     | $\overline{\text{OE}}$ | A       | B | C       | D |
| 2                | 3-state NAND | 3-state OR | L                      | input 1 | H | input 2 | L |
| 2                | 3-state NAND | 3-state OR | L                      | input 2 | H | input 1 | L |

[1] H = HIGH voltage level;  
L = LOW voltage level.

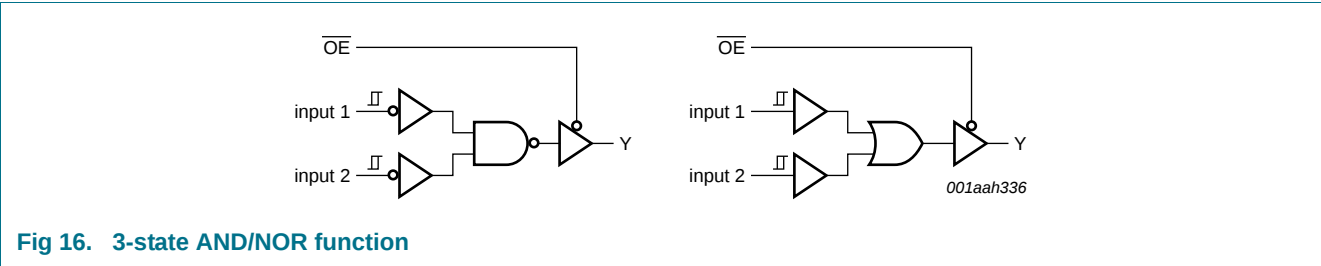


Fig 16. 3-state AND/NOR function

7.7 3-state XOR/XNOR functions available

Table 17. Function table<sup>[1]</sup>  
See [Figure 17](#).

| Function    | Input |         |         |         |         |
|-------------|-------|---------|---------|---------|---------|
|             | OE    | A       | B       | C       | D       |
| 3-state XOR | L     | input 1 | H or L  | L       | input 2 |
|             | L     | input 2 | H or L  | L       | input 1 |
|             | L     | H or L  | input 1 | H       | input 2 |
|             | L     | H or L  | input 2 | H       | input 1 |
|             | L     | L       | H       | input 1 | input 2 |
|             | L     | L       | H       | input 2 | input 1 |

[1] H = HIGH voltage level;  
L = LOW voltage level.

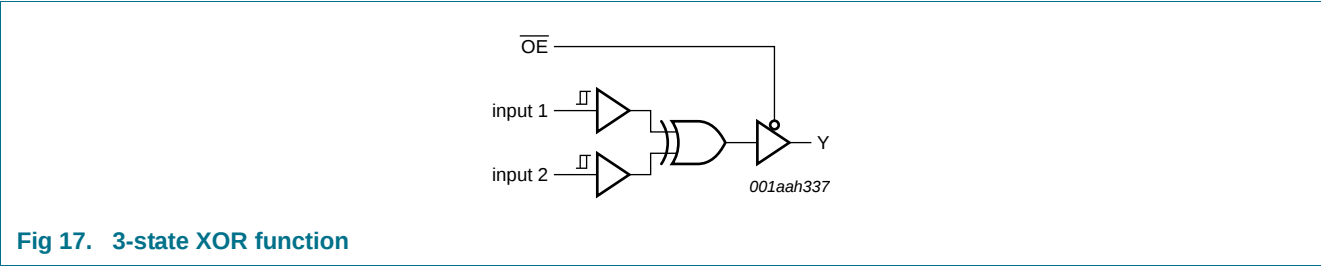


Table 18. Function table<sup>[1]</sup>  
See [Figure 18](#).

| Function    | Input |   |   |         |         |
|-------------|-------|---|---|---------|---------|
|             | OE    | A | B | C       | D       |
| 3-state XOR | L     | H | L | input 1 | input 2 |

[1] H = HIGH voltage level;  
L = LOW voltage level.

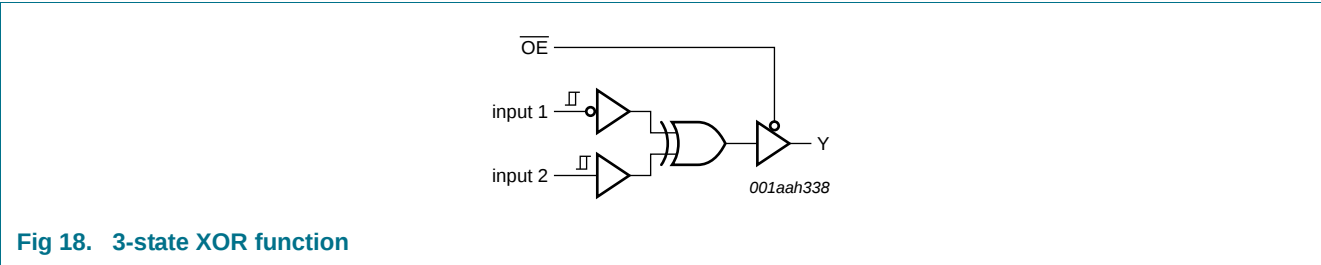


Table 19. Function table<sup>[1]</sup>

See [Figure 19](#).

| Function    | Input |   |   |         |         |
|-------------|-------|---|---|---------|---------|
|             | OE    | A | B | C       | D       |
| 3-state XOR | L     | H | L | input 1 | input 2 |

[1] H = HIGH voltage level;  
L = LOW voltage level.

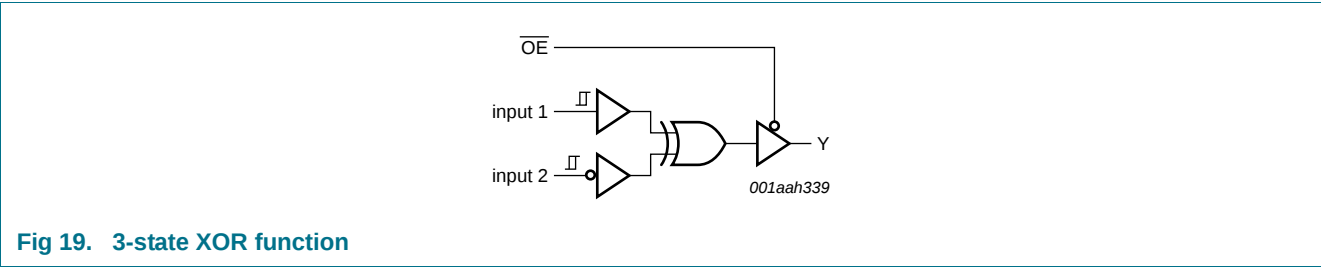
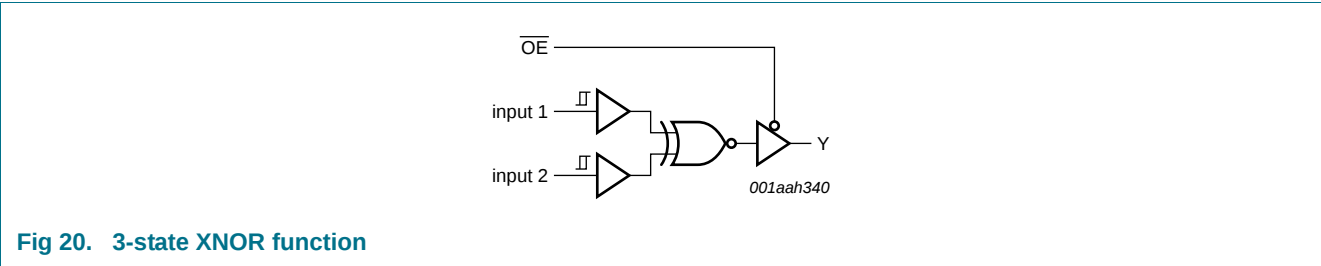


Table 20. Function table<sup>[1]</sup>

See [Figure 20](#).

| Function     | Input |   |   |         |         |
|--------------|-------|---|---|---------|---------|
|              | OE    | A | B | C       | D       |
| 3-state XNOR | L     | H | L | input 1 | input 2 |
|              | L     | H | L | input 2 | input 1 |

[1] H = HIGH voltage level;  
L = LOW voltage level.



## 8. Limiting values

**Table 21. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                      | Min         | Max            | Unit |
|-----------|-------------------------|---------------------------------|-------------|----------------|------|
| $V_{CC}$  | supply voltage          |                                 | -0.5        | +6.5           | V    |
| $I_{IK}$  | input clamping current  | $V_I < 0$ V                     | -50         | -              | mA   |
| $V_I$     | input voltage           |                                 | [1] -0.5    | +6.5           | V    |
| $I_{OK}$  | output clamping current | $V_O > V_{CC}$ or $V_O < 0$ V   | -           | $\pm 50$       | mA   |
| $V_O$     | output voltage          | Active mode                     | [1][2] -0.5 | $V_{CC} + 0.5$ | V    |
|           |                         | Power-down mode                 | [1][2] -0.5 | +6.5           | V    |
| $I_O$     | output current          | $V_O = 0$ V to $V_{CC}$         | -           | $\pm 50$       | mA   |
| $I_{CC}$  | supply current          |                                 | -           | 100            | mA   |
| $I_{GND}$ | ground current          |                                 | -100        | -              | mA   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to $+125$ °C | [3] -       | 250            | mW   |
| $T_{stg}$ | storage temperature     |                                 | -65         | +150           | °C   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When  $V_{CC} = 0$  V (Power-down mode), the output voltage can be 5.5 V in normal operation.

[3] For TSSOP8 package: above 110 °C the value of  $P_{tot}$  derates linearly with 8.0 mW/K.  
For XSON8 and XQFN8 packages: above 118 °C the value of  $P_{tot}$  derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

**Table 22. Operating conditions**

| Symbol              | Parameter                           | Conditions                      | Min  | Max      | Unit |
|---------------------|-------------------------------------|---------------------------------|------|----------|------|
| $V_{CC}$            | supply voltage                      |                                 | 1.65 | 5.5      | V    |
| $V_I$               | input voltage                       |                                 | 0    | 5.5      | V    |
| $V_O$               | output voltage                      | Active mode                     | 0    | $V_{CC}$ | V    |
|                     |                                     | Power-down mode; $V_{CC} = 0$ V | 0    | 5.5      | V    |
| $T_{amb}$           | ambient temperature                 |                                 | -40  | +125     | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 1.65$ V to $2.7$ V    | -    | 20       | ns/V |
|                     |                                     | $V_{CC} = 2.7$ V to $4.5$ V     | -    | 10       | ns/V |
|                     |                                     | $V_{CC} = 4.5$ V to $5.5$ V     | -    | 5        | ns/V |

## 10. Static characteristics

**Table 23. Static characteristics**

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                 | Conditions                                                                                                   | Min                   | Typ <sup>[1]</sup> | Max  | Unit |
|--------------------------------------------|---------------------------|--------------------------------------------------------------------------------------------------------------|-----------------------|--------------------|------|------|
| <b>T<sub>amb</sub> = –40 °C to +85 °C</b>  |                           |                                                                                                              |                       |                    |      |      |
| V <sub>OH</sub>                            | HIGH-level output voltage | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T–</sub>                                                          |                       |                    |      |      |
|                                            |                           | I <sub>O</sub> = –100 µA; V <sub>CC</sub> = 1.65 V to 5.5 V                                                  | V <sub>CC</sub> – 0.1 | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = –4 mA; V <sub>CC</sub> = 1.65 V                                                             | 1.2                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = –8 mA; V <sub>CC</sub> = 2.3 V                                                              | 1.9                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = –12 mA; V <sub>CC</sub> = 2.7 V                                                             | 2.2                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = –24 mA; V <sub>CC</sub> = 3.0 V                                                             | 2.3                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = –32 mA; V <sub>CC</sub> = 4.5 V                                                             | 3.8                   | -                  | -    | V    |
| V <sub>OL</sub>                            | LOW-level output voltage  | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T–</sub>                                                          |                       |                    |      |      |
|                                            |                           | I <sub>O</sub> = 100 µA; V <sub>CC</sub> = 1.65 V to 5.5 V                                                   | -                     | -                  | 0.1  | V    |
|                                            |                           | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V                                                              | -                     | -                  | 0.45 | V    |
|                                            |                           | I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V                                                               | -                     | -                  | 0.3  | V    |
|                                            |                           | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V                                                              | -                     | -                  | 0.4  | V    |
|                                            |                           | I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V                                                              | -                     | -                  | 0.55 | V    |
|                                            |                           | I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V                                                              | -                     | -                  | 0.55 | V    |
| I <sub>I</sub>                             | input leakage current     | V <sub>CC</sub> = 0 V to 5.5 V; V <sub>I</sub> = 5.5 V or GND                                                | -                     | ±0.1               | ±5   | µA   |
| I <sub>OZ</sub>                            | OFF-state output current  | V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 5.5 V or GND | -                     | ±0.1               | ±10  | µA   |
| I <sub>OFF</sub>                           | power-off leakage current | V <sub>CC</sub> = 0 V; V <sub>I</sub> or V <sub>O</sub> = 5.5 V                                              | -                     | ±0.1               | ±10  | µA   |
| I <sub>CC</sub>                            | supply current            | V <sub>CC</sub> = 1.65 V to 5.5 V; V <sub>I</sub> = 5.5 V or GND; I <sub>O</sub> = 0 A                       | -                     | 0.1                | 10   | µA   |
| ΔI <sub>CC</sub>                           | additional supply current | per pin; V <sub>CC</sub> = 2.3 V to 5.5 V; V <sub>I</sub> = V <sub>CC</sub> – 0.6 V; I <sub>O</sub> = 0 A    | -                     | 5                  | 500  | µA   |
| C <sub>I</sub>                             | input capacitance         | V <sub>CC</sub> = 3.3 V; V <sub>I</sub> = GND to V <sub>CC</sub>                                             | -                     | 2.5                | -    | pF   |
| <b>T<sub>amb</sub> = –40 °C to +125 °C</b> |                           |                                                                                                              |                       |                    |      |      |
| V <sub>OH</sub>                            | HIGH-level output voltage | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T–</sub>                                                          |                       |                    |      |      |
|                                            |                           | I <sub>O</sub> = –100 µA; V <sub>CC</sub> = 1.65 V to 5.5 V                                                  | V <sub>CC</sub> – 0.1 | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = –4 mA; V <sub>CC</sub> = 1.65 V                                                             | 0.95                  | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = –8 mA; V <sub>CC</sub> = 2.3 V                                                              | 1.7                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = –12 mA; V <sub>CC</sub> = 2.7 V                                                             | 1.9                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = –24 mA; V <sub>CC</sub> = 3.0 V                                                             | 2.0                   | -                  | -    | V    |
|                                            |                           | I <sub>O</sub> = –32 mA; V <sub>CC</sub> = 4.5 V                                                             | 3.4                   | -                  | -    | V    |
| V <sub>OL</sub>                            | LOW-level output voltage  | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T–</sub>                                                          |                       |                    |      |      |
|                                            |                           | I <sub>O</sub> = 100 µA; V <sub>CC</sub> = 1.65 V to 5.5 V                                                   | -                     | -                  | 0.1  | V    |
|                                            |                           | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V                                                              | -                     | -                  | 0.70 | V    |
|                                            |                           | I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V                                                               | -                     | -                  | 0.45 | V    |
|                                            |                           | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V                                                              | -                     | -                  | 0.60 | V    |
|                                            |                           | I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V                                                              | -                     | -                  | 0.80 | V    |
|                                            |                           | I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V                                                              | -                     | -                  | 0.80 | V    |

**Table 23. Static characteristics ...continued**

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter                 | Conditions                                                                                               | Min | Typ <sup>[1]</sup> | Max       | Unit          |
|-----------------|---------------------------|----------------------------------------------------------------------------------------------------------|-----|--------------------|-----------|---------------|
| $I_I$           | input leakage current     | $V_{CC} = 0\text{ V to }5.5\text{ V}$ ; $V_I = 5.5\text{ V or GND}$                                      | -   | -                  | $\pm 100$ | $\mu\text{A}$ |
| $I_{OZ}$        | OFF-state output current  | $V_{CC} = 3.6\text{ V}$ ; $V_I = V_{IH}\text{ or }V_{IL}$ ;<br>$V_O = 5.5\text{ V or GND}$               | -   | -                  | $\pm 200$ | $\mu\text{A}$ |
| $I_{OFF}$       | power-off leakage current | $V_{CC} = 0\text{ V}$ ; $V_I\text{ or }V_O = 5.5\text{ V}$                                               | -   | -                  | $\pm 200$ | $\mu\text{A}$ |
| $I_{CC}$        | supply current            | $V_{CC} = 1.65\text{ V to }5.5\text{ V}$ ;<br>$V_I = 5.5\text{ V or GND}$ ; $I_O = 0\text{ A}$           | -   | -                  | 200       | $\mu\text{A}$ |
| $\Delta I_{CC}$ | additional supply current | per pin; $V_{CC} = 2.3\text{ V to }5.5\text{ V}$ ;<br>$V_I = V_{CC} - 0.6\text{ V}$ ; $I_O = 0\text{ A}$ | -   | -                  | 5000      | $\mu\text{A}$ |

[1] All typical values are measured at  $V_{CC} = 3.3\text{ V}$  and  $T_{amb} = 25\text{ }^\circ\text{C}$ .

## 11. Dynamic characteristics

**Table 24. Dynamic characteristics**Voltages are referenced to GND (ground = 0 V; for test circuit see [Figure 23](#)).

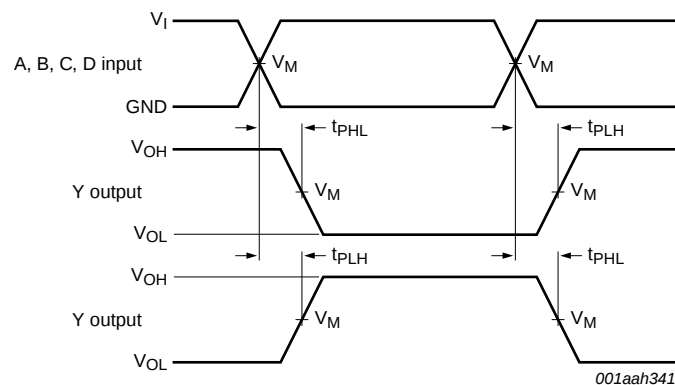
| Symbol   | Parameter         | Conditions                                           | 25 °C |                    |     | -40 °C to +125 °C |             |              | Unit |
|----------|-------------------|------------------------------------------------------|-------|--------------------|-----|-------------------|-------------|--------------|------|
|          |                   |                                                      | Min   | Typ <sup>[1]</sup> | Max | Min               | Max (85 °C) | Max (125 °C) |      |
| $t_{pd}$ | propagation delay | A to Y; see <a href="#">Figure 21</a> <sup>[2]</sup> |       |                    |     |                   |             |              |      |
|          |                   | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$            | -     | 7.5                | -   | 2.8               | 30.8        | 38.5         | ns   |
|          |                   | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$              | -     | 5.0                | -   | 2.0               | 11.7        | 14.6         | ns   |
|          |                   | $V_{CC} = 2.7\text{ V}$                              | -     | 5.4                | -   | 2.0               | 9.0         | 11.3         | ns   |
|          |                   | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$              | -     | 4.5                | -   | 1.8               | 8.4         | 10.5         | ns   |
|          |                   | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$              | -     | 3.8                | -   | 1.8               | 5.5         | 6.9          | ns   |
|          |                   | B to Y; see <a href="#">Figure 21</a> <sup>[2]</sup> |       |                    |     |                   |             |              |      |
|          |                   | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$            | -     | 7.5                | -   | 2.8               | 28.9        | 36.2         | ns   |
|          |                   | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$              | -     | 5.0                | -   | 2.0               | 11.3        | 14.2         | ns   |
|          |                   | $V_{CC} = 2.7\text{ V}$                              | -     | 5.4                | -   | 2.0               | 9.0         | 11.3         | ns   |
|          |                   | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$              | -     | 4.5                | -   | 1.8               | 8.2         | 10.3         | ns   |
|          |                   | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$              | -     | 3.8                | -   | 1.8               | 5.4         | 6.8          | ns   |
|          |                   | C to Y; see <a href="#">Figure 21</a> <sup>[2]</sup> |       |                    |     |                   |             |              |      |
|          |                   | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$            | -     | 7.8                | -   | 3.2               | 29.8        | 37.3         | ns   |
|          |                   | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$              | -     | 5.2                | -   | 2.3               | 12.3        | 15.4         | ns   |
|          |                   | $V_{CC} = 2.7\text{ V}$                              | -     | 5.3                | -   | 2.3               | 9.6         | 12.0         | ns   |
|          |                   | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$              | -     | 4.6                | -   | 2.3               | 8.6         | 10.8         | ns   |
|          |                   | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$              | -     | 3.8                | -   | 1.8               | 5.7         | 7.2          | ns   |
|          |                   | D to Y; see <a href="#">Figure 21</a> <sup>[2]</sup> |       |                    |     |                   |             |              |      |
|          |                   | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$            | -     | 7.0                | -   | 2.8               | 25.7        | 32.2         | ns   |
|          |                   | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$              | -     | 4.6                | -   | 2.0               | 10.7        | 13.4         | ns   |
|          |                   | $V_{CC} = 2.7\text{ V}$                              | -     | 4.8                | -   | 2.0               | 9.2         | 11.5         | ns   |
|          |                   | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$              | -     | 4.1                | -   | 1.8               | 7.6         | 9.5          | ns   |
|          |                   | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$              | -     | 3.4                | -   | 1.6               | 5.2         | 6.5          | ns   |

**Table 24. Dynamic characteristics ...continued**Voltages are referenced to GND (ground = 0 V; for test circuit see [Figure 23](#)).

| Symbol    | Parameter                     | Conditions                                                                                                              | 25 °C |                    |     | –40 °C to +125 °C |             |              | Unit |
|-----------|-------------------------------|-------------------------------------------------------------------------------------------------------------------------|-------|--------------------|-----|-------------------|-------------|--------------|------|
|           |                               |                                                                                                                         | Min   | Typ <sup>[1]</sup> | Max | Min               | Max (85 °C) | Max (125 °C) |      |
| $t_{en}$  | enable time                   | $\overline{OE}$ to Y; see <a href="#">Figure 22</a> <sup>[3]</sup>                                                      |       |                    |     |                   |             |              |      |
|           |                               | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$                                                                               | -     | 5.7                | -   | 2.0               | 25.2        | 32.0         | ns   |
|           |                               | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$                                                                                 | -     | 3.8                | -   | 1.4               | 11.3        | 14.0         | ns   |
|           |                               | $V_{CC} = 2.7\text{ V}$                                                                                                 | -     | 4.2                | -   | 1.4               | 8.6         | 11.0         | ns   |
|           |                               | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$                                                                                 | -     | 3.5                | -   | 1.4               | 7.0         | 9.0          | ns   |
|           |                               | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$                                                                                 | -     | 2.7                | -   | 1.4               | 4.7         | 6.0          | ns   |
| $t_{dis}$ | disable time                  | $\overline{OE}$ to Y; see <a href="#">Figure 22</a> <sup>[4]</sup>                                                      |       |                    |     |                   |             |              |      |
|           |                               | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$                                                                               | -     | 5.7                | -   | 3.0               | 15.0        | 19.0         | ns   |
|           |                               | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$                                                                                 | -     | 3.6                | -   | 2.0               | 5.8         | 7.3          | ns   |
|           |                               | $V_{CC} = 2.7\text{ V}$                                                                                                 | -     | 4.5                | -   | 2.0               | 6.6         | 8.2          | ns   |
|           |                               | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$                                                                                 | -     | 4.5                | -   | 2.1               | 5.9         | 7.4          | ns   |
|           |                               | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$                                                                                 | -     | 3.4                | -   | 1.0               | 4.5         | 5.6          | ns   |
| $C_{PD}$  | power dissipation capacitance | per buffer (output enabled); $f_i = 10\text{ MHz}$ ; $C_L = 50\text{ pF}$ ; $V_i = \text{GND to }V_{CC}$ <sup>[5]</sup> |       |                    |     |                   |             |              |      |
|           |                               | $V_{CC} = 1.65\text{ V to }1.95\text{ V}$                                                                               | -     | 14                 | -   | -                 | -           | -            | pF   |
|           |                               | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$                                                                                 | -     | 16                 | -   | -                 | -           | -            | pF   |
|           |                               | $V_{CC} = 2.7\text{ V}$                                                                                                 | -     | 18                 | -   | -                 | -           | -            | pF   |
|           |                               | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$                                                                                 | -     | 25                 | -   | -                 | -           | -            | pF   |
|           |                               | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$                                                                                 | -     | 30                 | -   | -                 | -           | -            | pF   |

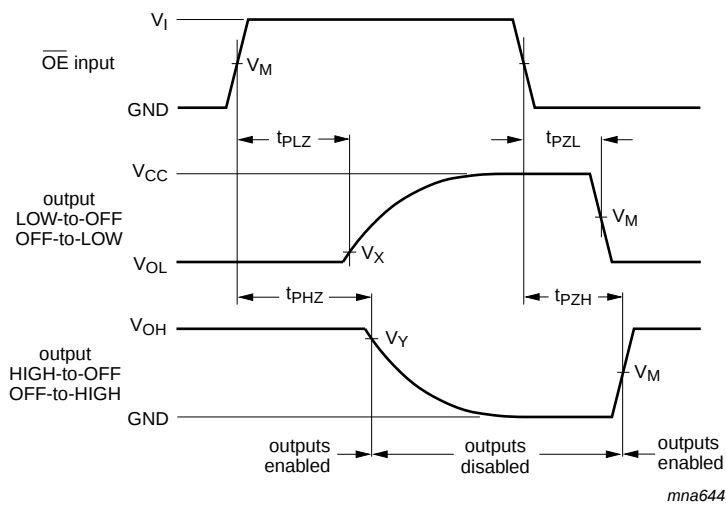
[1] All typical values are measured at nominal  $V_{CC}$ .[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .[3]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .[4]  $t_{dis}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .[5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where: $f_i$  = input frequency in MHz; $f_o$  = output frequency in MHz; $C_L$  = output load capacitance in pF; $V_{CC}$  = supply voltage in V; $N$  = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

12. Waveforms



Measurement points are given in [Table 25](#).  
Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig 21. The data input (A, B, C, D) to output (Y) propagation delays

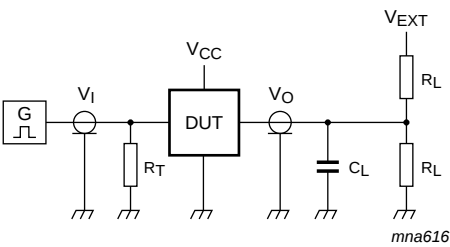


Measurement points are given in [Table 25](#).  
Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig 22. 3-state enable and disable times

Table 25. Measurement points

| Supply voltage   | Input       | Output      |                          |                          |
|------------------|-------------|-------------|--------------------------|--------------------------|
| $V_{CC}$         | $V_M$       | $V_M$       | $V_X$                    | $V_Y$                    |
| 1.65 V to 1.95 V | $0.5V_{CC}$ | $0.5V_{CC}$ | $V_{OL} + 0.15\text{ V}$ | $V_{OH} - 0.15\text{ V}$ |
| 2.3 V to 2.7 V   | $0.5V_{CC}$ | $0.5V_{CC}$ | $V_{OL} + 0.15\text{ V}$ | $V_{OH} - 0.15\text{ V}$ |
| 2.7 V            | 1.5 V       | 1.5 V       | $V_{OL} + 0.3\text{ V}$  | $V_{OH} - 0.3\text{ V}$  |
| 3.0 V to 3.6 V   | 1.5 V       | 1.5 V       | $V_{OL} + 0.3\text{ V}$  | $V_{OH} - 0.3\text{ V}$  |
| 4.5 V to 5.5 V   | $0.5V_{CC}$ | $0.5V_{CC}$ | $V_{OL} + 0.3\text{ V}$  | $V_{OH} - 0.3\text{ V}$  |



Test data is given in [Table 26](#).  
Definitions for test circuit:  
 $R_L$  = Load resistance.  
 $C_L$  = Load capacitance including jig and probe capacitance.  
 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.  
 $V_{EXT}$  = External voltage for measuring switching times.

Fig 23. Test circuit for measuring switching times

Table 26. Test data

| Supply voltage   | Input    |               | Load  |              | $V_{EXT}$          |                    |                    |
|------------------|----------|---------------|-------|--------------|--------------------|--------------------|--------------------|
|                  | $V_I$    | $t_r = t_f$   | $C_L$ | $R_L$        | $t_{PLH}, t_{PHL}$ | $t_{PZH}, t_{PHZ}$ | $t_{PZL}, t_{PLZ}$ |
| 1.65 V to 1.95 V | $V_{CC}$ | $\leq 2.0$ ns | 30 pF | 1 k $\Omega$ | open               | GND                | $2V_{CC}$          |
| 2.3 V to 2.7 V   | $V_{CC}$ | $\leq 2.0$ ns | 30 pF | 500 $\Omega$ | open               | GND                | $2V_{CC}$          |
| 2.7 V            | 2.7 V    | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               | GND                | 6 V                |
| 3.0 V to 3.6 V   | 2.7 V    | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               | GND                | 6 V                |
| 4.5 V to 5.5 V   | $V_{CC}$ | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               | GND                | $2V_{CC}$          |

13. Transfer characteristics

Table 27. Transfer characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see [Figure 23](#))

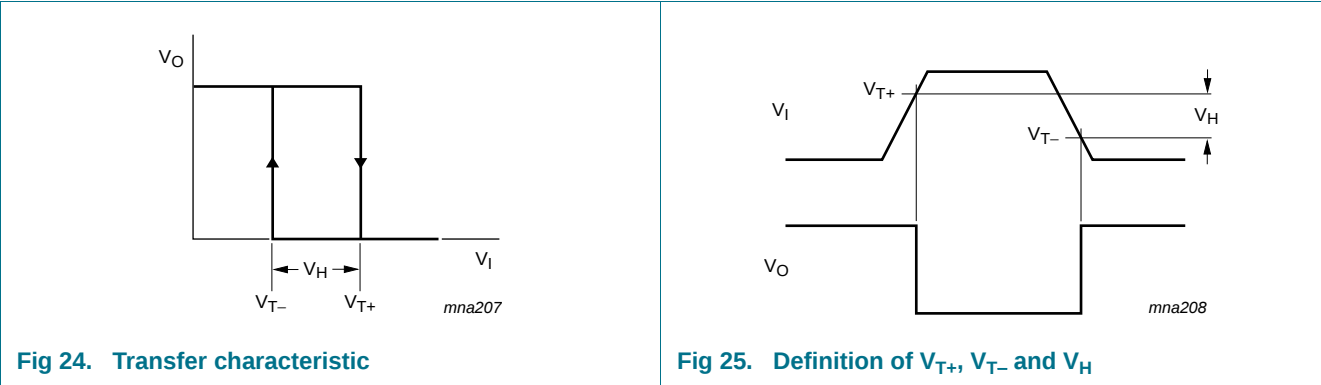
| Symbol   | Parameter                        | Conditions                                                                                                                                      | −40 °C to +85 °C |                    |      | −40 °C to +125 °C |      | Unit |
|----------|----------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------|------------------|--------------------|------|-------------------|------|------|
|          |                                  |                                                                                                                                                 | Min              | Typ <sup>[1]</sup> | Max  | Min               | Max  |      |
| $V_{T+}$ | positive-going threshold voltage | see <a href="#">Figure 24</a> , <a href="#">Figure 25</a> , <a href="#">Figure 26</a> , <a href="#">Figure 27</a> and <a href="#">Figure 28</a> |                  |                    |      |                   |      |      |
|          |                                  | $V_{CC} = 1.8$ V                                                                                                                                | 0.70             | 1.02               | 1.20 | 0.67              | 1.20 | V    |
|          |                                  | $V_{CC} = 2.3$ V                                                                                                                                | 1.11             | 1.42               | 1.60 | 1.08              | 1.60 | V    |
|          |                                  | $V_{CC} = 3.0$ V                                                                                                                                | 1.50             | 1.79               | 2.00 | 1.47              | 2.00 | V    |
|          |                                  | $V_{CC} = 4.5$ V                                                                                                                                | 2.16             | 2.52               | 2.74 | 2.13              | 2.74 | V    |
|          |                                  | $V_{CC} = 5.5$ V                                                                                                                                | 2.61             | 2.99               | 3.33 | 2.58              | 3.33 | V    |

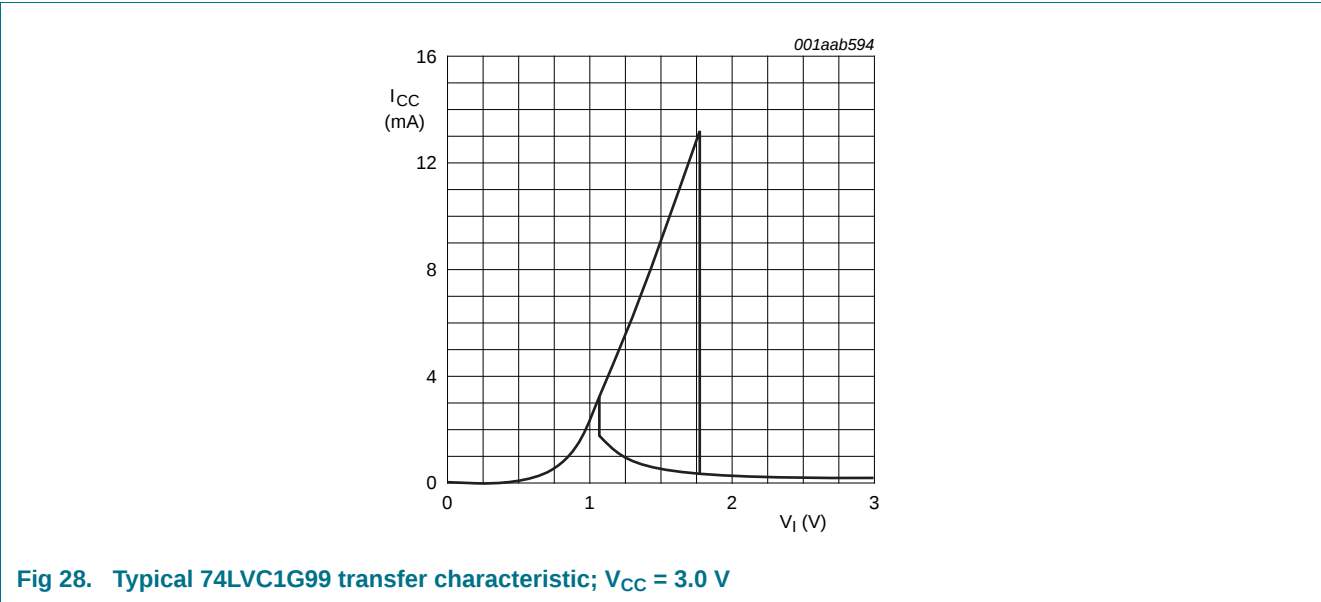
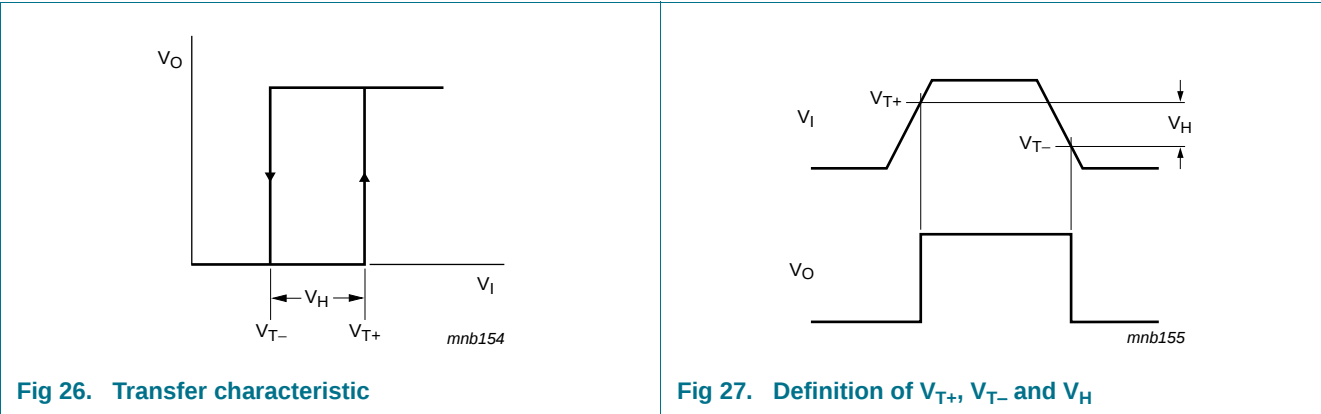
**Table 27. Transfer characteristics ...continued**  
 Voltages are referenced to GND (ground = 0 V; for test circuit see [Figure 23](#)

| Symbol          | Parameter                        | Conditions                                                                                                                                                                            | –40 °C to +85 °C |                    |      | –40 °C to +125 °C |      | Unit |
|-----------------|----------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------|--------------------|------|-------------------|------|------|
|                 |                                  |                                                                                                                                                                                       | Min              | Typ <sup>[1]</sup> | Max  | Min               | Max  |      |
| V <sub>T–</sub> | negative-going threshold voltage | see <a href="#">Figure 24</a> , <a href="#">Figure 25</a> , <a href="#">Figure 26</a> , <a href="#">Figure 27</a> and <a href="#">Figure 28</a>                                       |                  |                    |      |                   |      |      |
|                 |                                  | V <sub>CC</sub> = 1.8 V                                                                                                                                                               | 0.30             | 0.53               | 0.72 | 0.30              | 0.75 | V    |
|                 |                                  | V <sub>CC</sub> = 2.3 V                                                                                                                                                               | 0.58             | 0.77               | 1.00 | 0.58              | 1.03 | V    |
|                 |                                  | V <sub>CC</sub> = 3.0 V                                                                                                                                                               | 0.80             | 1.04               | 1.30 | 0.80              | 1.33 | V    |
|                 |                                  | V <sub>CC</sub> = 4.5 V                                                                                                                                                               | 1.21             | 1.55               | 1.90 | 1.21              | 1.93 | V    |
|                 |                                  | V <sub>CC</sub> = 5.5 V                                                                                                                                                               | 1.45             | 1.86               | 2.29 | 1.45              | 2.32 | V    |
| V <sub>H</sub>  | hysteresis voltage               | (V <sub>T+</sub> – V <sub>T–</sub> ); see <a href="#">Figure 24</a> , <a href="#">Figure 25</a> , <a href="#">Figure 26</a> , <a href="#">Figure 27</a> and <a href="#">Figure 28</a> |                  |                    |      |                   |      |      |
|                 |                                  | V <sub>CC</sub> = 1.8 V                                                                                                                                                               | 0.30             | 0.48               | 0.62 | 0.23              | 0.62 | V    |
|                 |                                  | V <sub>CC</sub> = 2.3 V                                                                                                                                                               | 0.40             | 0.64               | 0.80 | 0.34              | 0.80 | V    |
|                 |                                  | V <sub>CC</sub> = 3.0 V                                                                                                                                                               | 0.50             | 0.75               | 1.00 | 0.44              | 1.00 | V    |
|                 |                                  | V <sub>CC</sub> = 4.5 V                                                                                                                                                               | 0.71             | 0.97               | 1.20 | 0.65              | 1.20 | V    |
|                 |                                  | V <sub>CC</sub> = 5.5 V                                                                                                                                                               | 0.71             | 1.13               | 1.40 | 0.65              | 1.40 | V    |

[1] All typical values are measured at T<sub>amb</sub> = 25 °C

## 14. Waveforms transfer characteristics





15. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm    SOT505-2

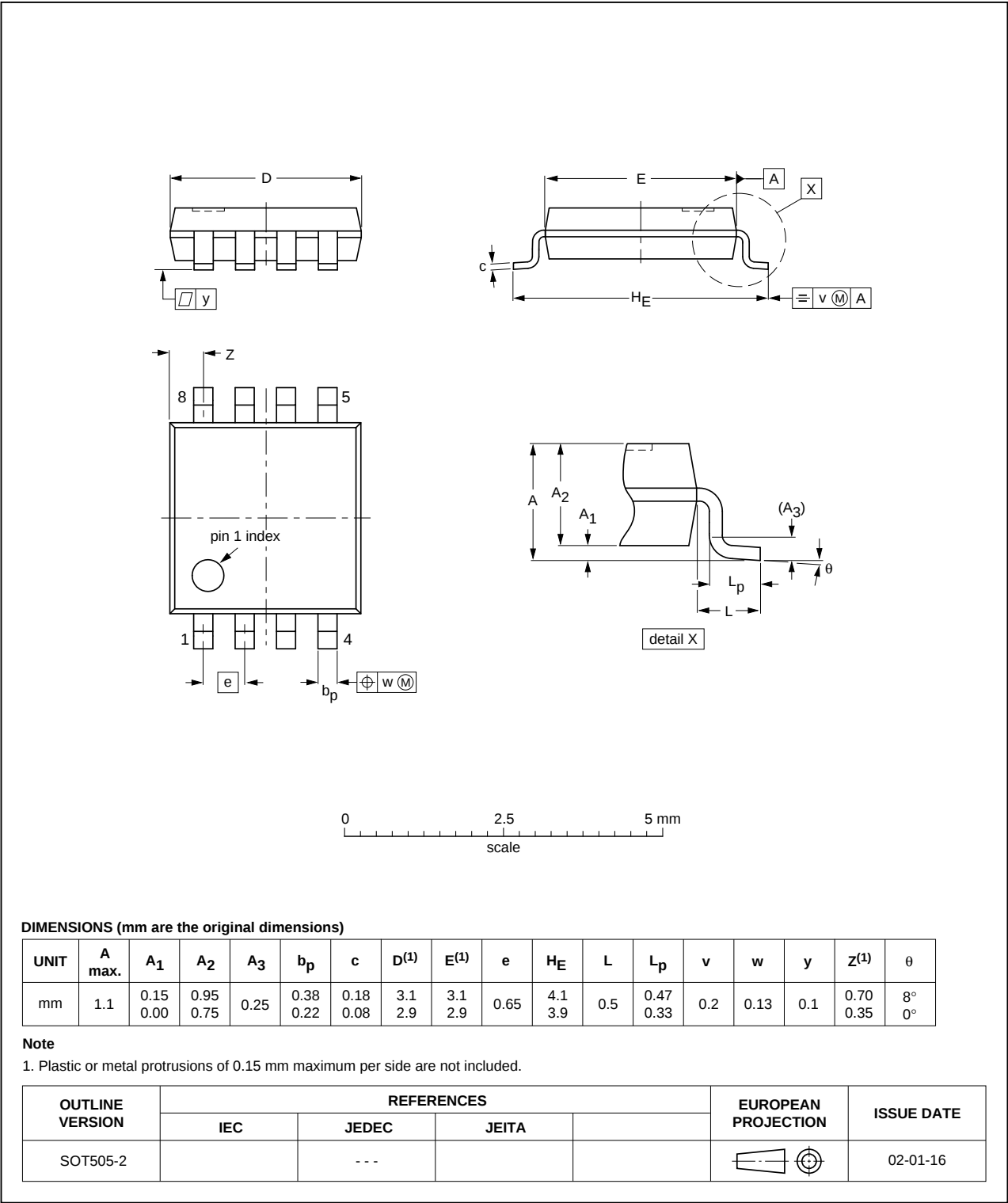


Fig 29. Package outline SOT505-2 (TSSOP8)

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm

SOT833-1

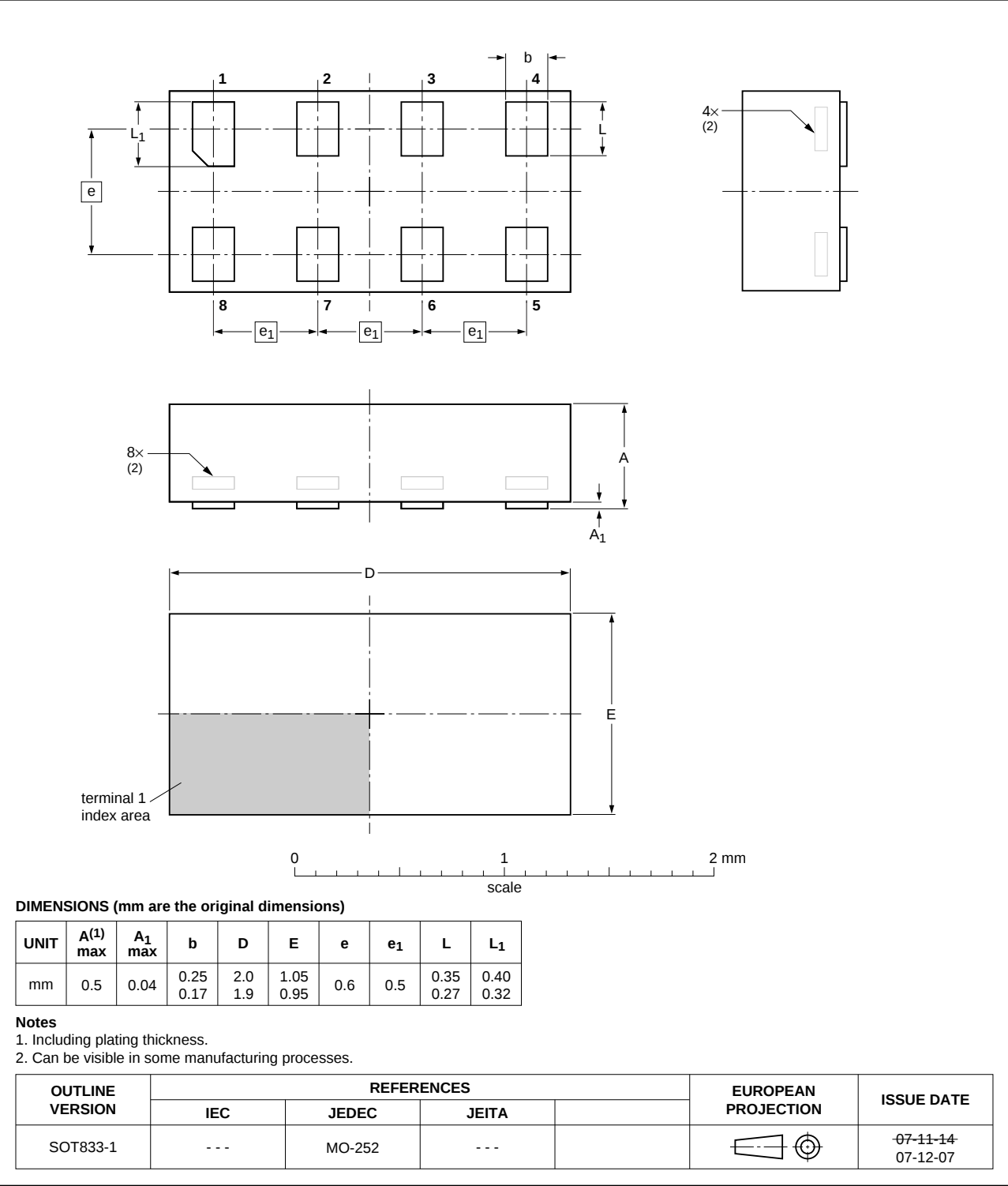


Fig 30. Package outline SOT833-1 (XSON8)

XSON8: extremely thin small outline package; no leads;  
8 terminals; body 1.35 x 1 x 0.5 mm

SOT1089

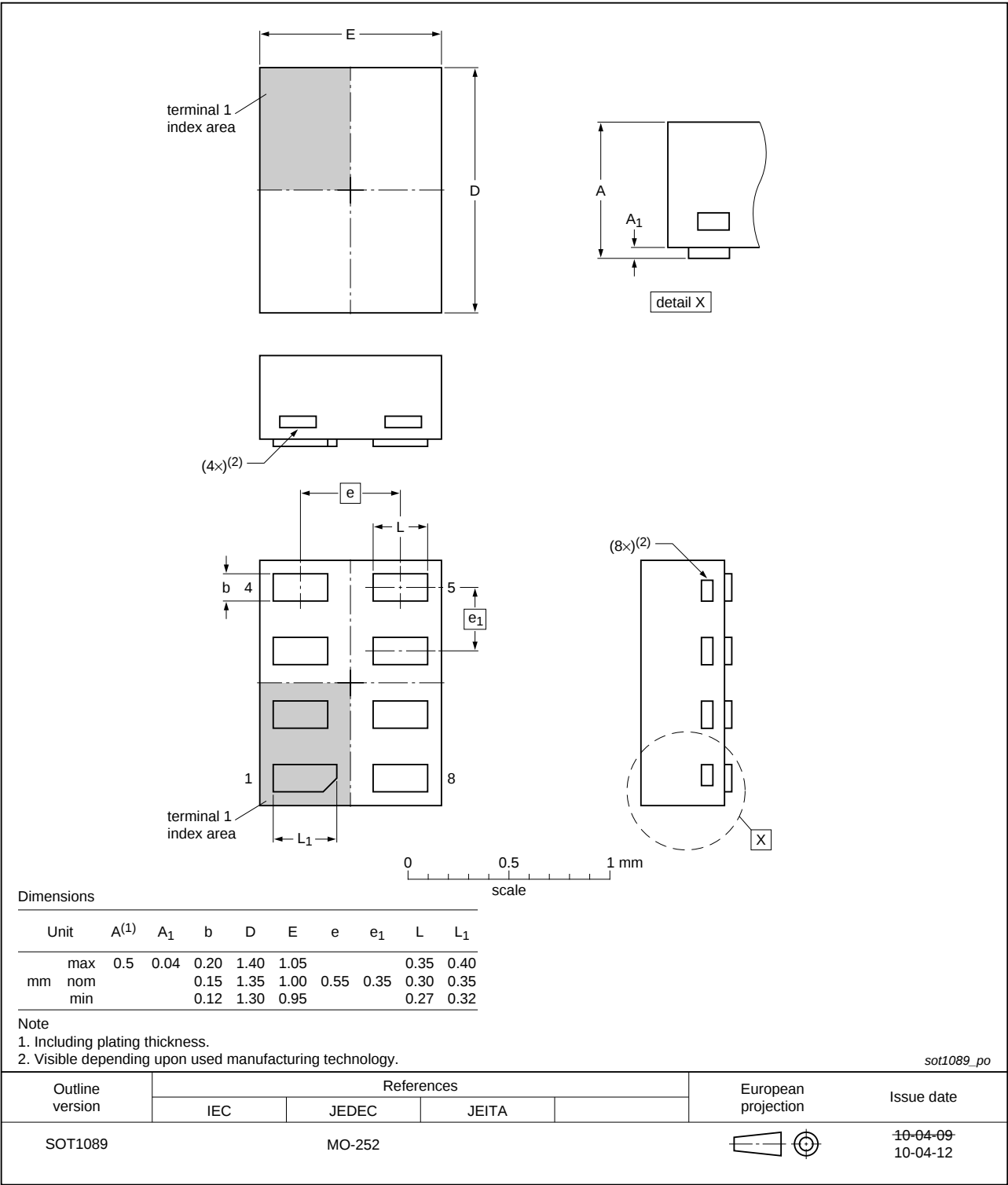


Fig 31. Package outline SOT1089 (XSON8)

XSON8: plastic extremely thin small outline package; no leads;  
8 terminals; body 3 x 2 x 0.5 mm

SOT996-2

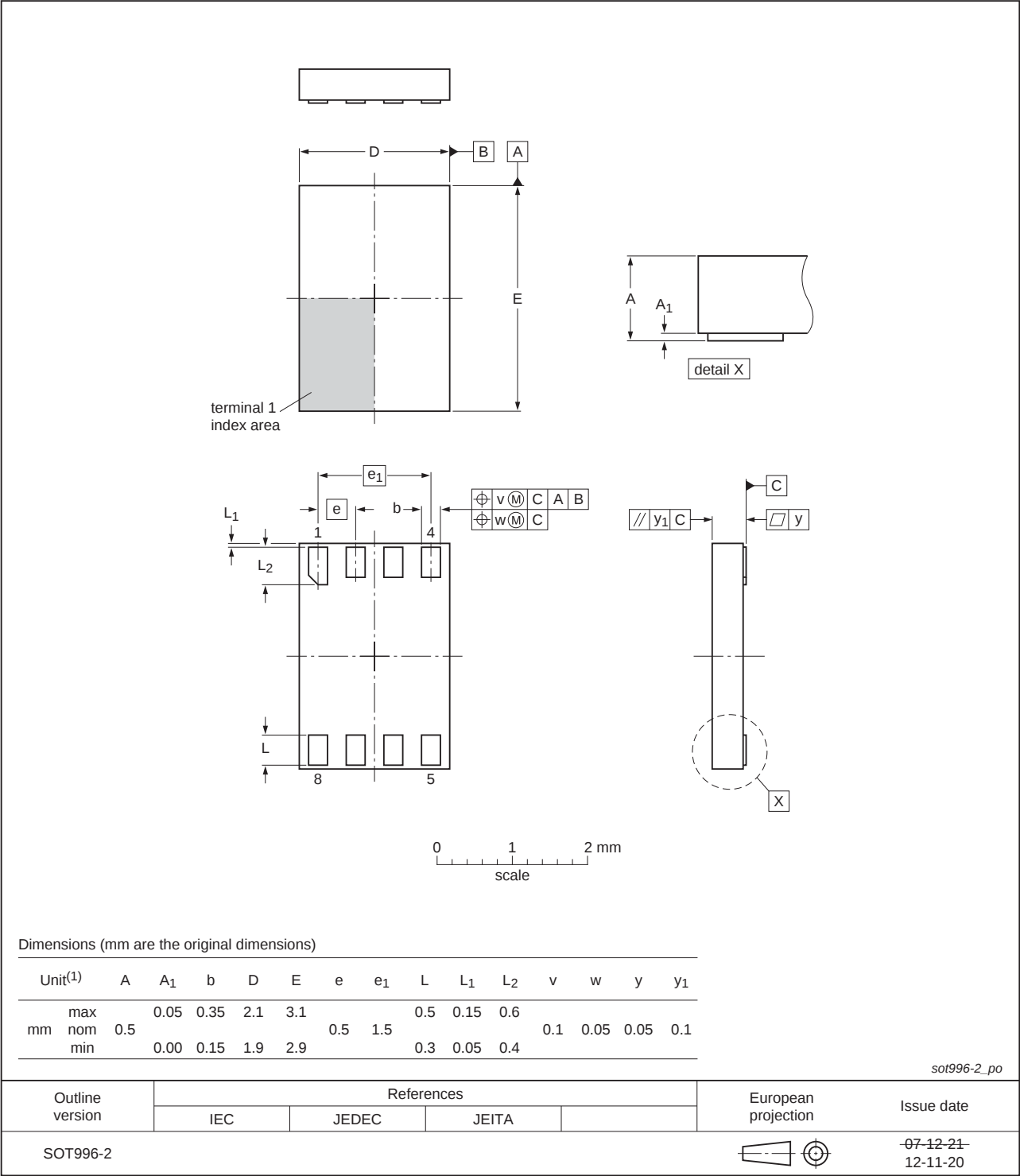


Fig 32. Package outline SOT996-2 (XSON8)

XQFN8: plastic, extremely thin quad flat package; no leads;  
8 terminals; body 1.6 x 1.6 x 0.5 mm

SOT902-2

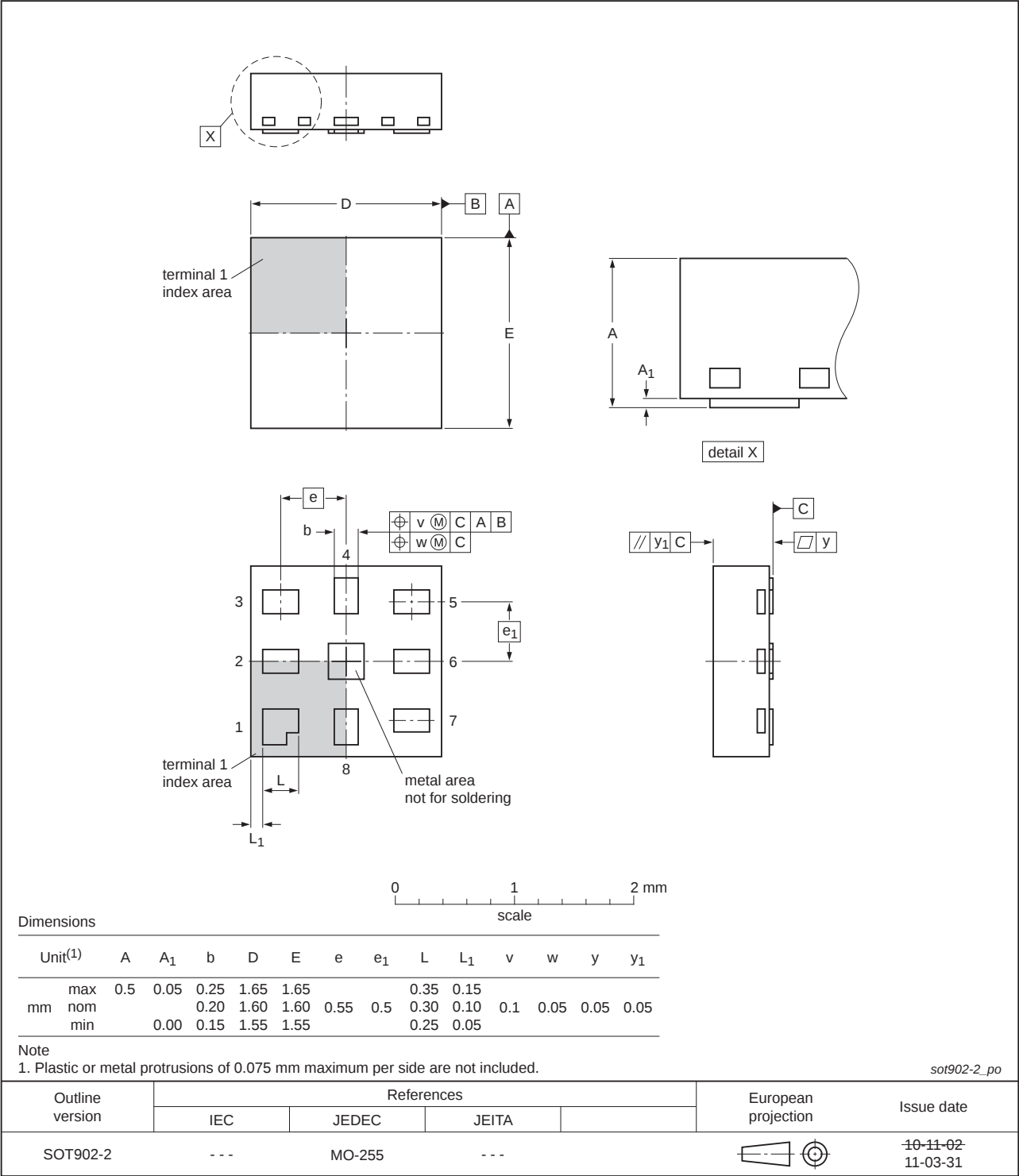


Fig 33. Package outline SOT902-2 (XQFN8)

XSON8: extremely thin small outline package; no leads;  
8 terminals; body 1.2 x 1.0 x 0.35 mm

SOT1116

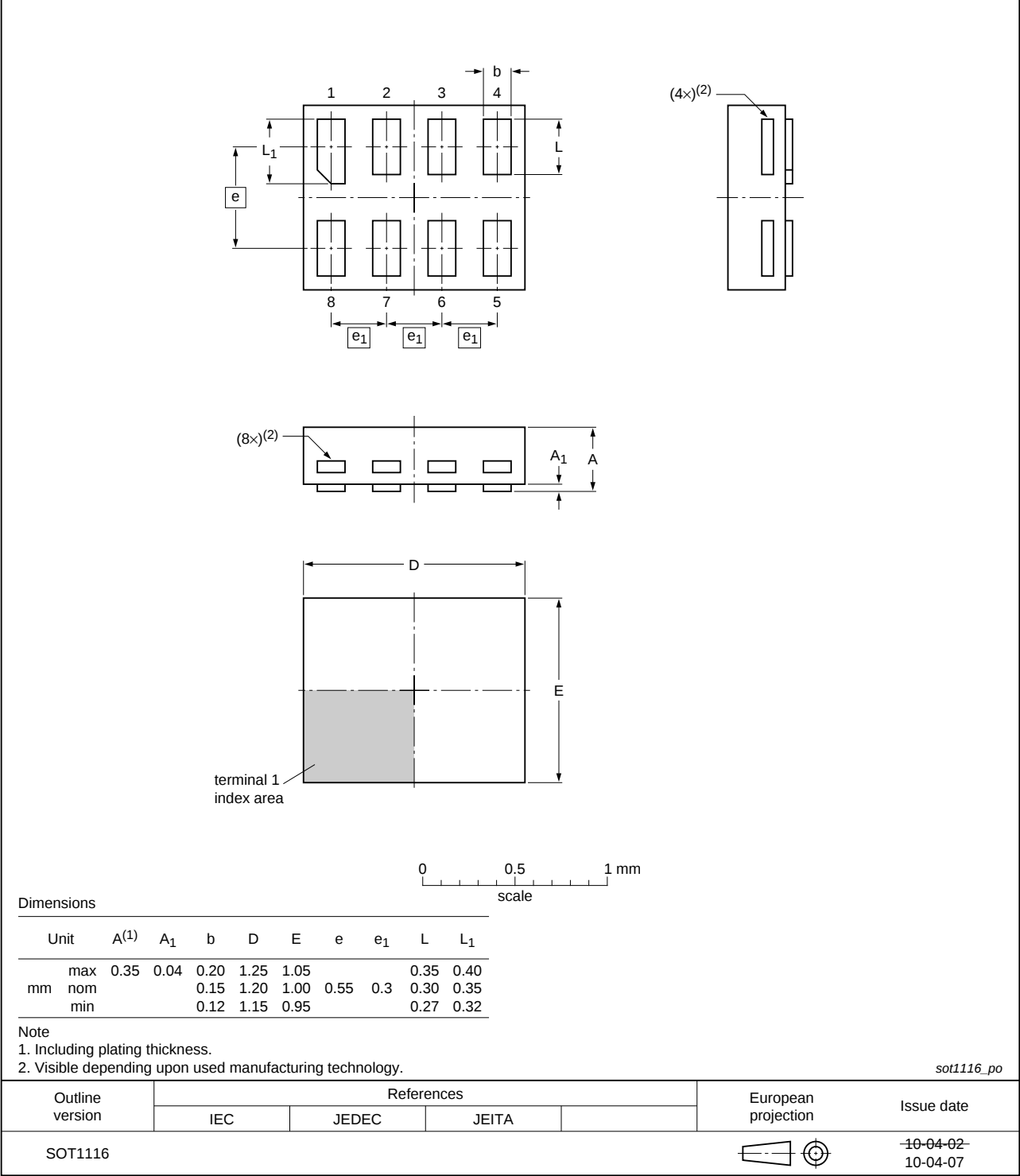
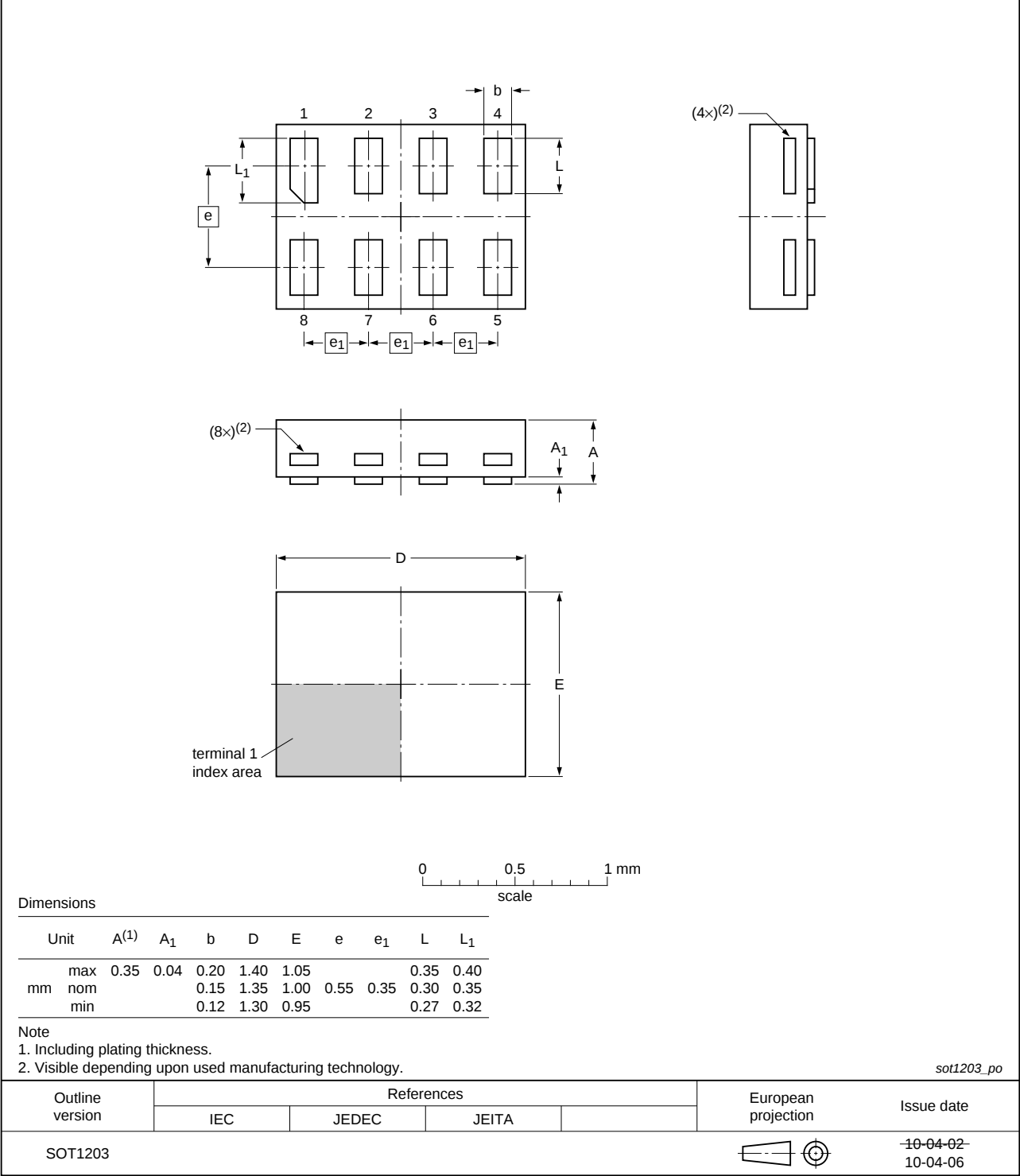


Fig 34. Package outline SOT1116 (XSON8)

XSON8: extremely thin small outline package; no leads;  
8 terminals; body 1.35 x 1.0 x 0.35 mm

SOT1203



## 16. Abbreviations

Table 28. Abbreviations

| Acronym | Description                             |
|---------|-----------------------------------------|
| CMOS    | Complementary Metal-Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MM      | Machine Model                           |
| TTL     | Transistor-Transistor Logic             |

## 17. Revision history

Table 29. Revision history

| Document ID    | Release date                                                        | Data sheet status  | Change notice | Supersedes    |
|----------------|---------------------------------------------------------------------|--------------------|---------------|---------------|
| 74LVC1G99 v.8  | 20130405                                                            | Product data sheet | -             | 74LVC1G99 v.7 |
| Modifications: | • For type number 74LVC1G99GD XSON8U has changed to XSON8.          |                    |               |               |
| 74LVC1G99 v.7  | 20120622                                                            | Product data sheet | -             | 74LVC1G99 v.6 |
| Modifications: | • For type number 74LVC1G99GM the SOT code has changed to SOT902-2. |                    |               |               |
| 74LVC1G99 v.6  | 20111201                                                            | Product data sheet | -             | 74LVC1G99 v.5 |
| Modifications: | • Legal pages updated.                                              |                    |               |               |
| 74LVC1G99 v.5  | 20101021                                                            | Product data sheet | -             | 74LVC1G99 v.4 |
| 74LVC1G99 v.4  | 20100416                                                            | Product data sheet | -             | 74LVC1G99 v.3 |
| 74LVC1G99 v.3  | 20091203                                                            | Product data sheet | -             | 74LVC1G99 v.2 |
| 74LVC1G99 v.2  | 20080208                                                            | Product data sheet | -             | 74LVC1G99 v.1 |
| 74LVC1G99 v.1  | 20080103                                                            | Product data sheet | -             | -             |

## 18. Legal information

### 18.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

### 18.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

**Short data sheet** — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

### 18.3 Disclaimers

**Limited warranty and liability** — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

**Right to make changes** — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

**Limiting values** — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

**Terms and conditions of commercial sale** — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nxp.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Non-automotive qualified products** — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the

product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

## 18.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## 19. Contact information

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

## 20. Contents

|           |                                                     |           |
|-----------|-----------------------------------------------------|-----------|
| <b>1</b>  | <b>General description</b> . . . . .                | <b>1</b>  |
| <b>2</b>  | <b>Features and benefits</b> . . . . .              | <b>1</b>  |
| <b>3</b>  | <b>Ordering information</b> . . . . .               | <b>2</b>  |
| <b>4</b>  | <b>Marking</b> . . . . .                            | <b>2</b>  |
| <b>5</b>  | <b>Functional diagram</b> . . . . .                 | <b>3</b>  |
| <b>6</b>  | <b>Pinning information</b> . . . . .                | <b>3</b>  |
| 6.1       | Pinning . . . . .                                   | 3         |
| 6.2       | Pin description . . . . .                           | 4         |
| <b>7</b>  | <b>Functional description</b> . . . . .             | <b>5</b>  |
| 7.1       | Logic configurations . . . . .                      | 6         |
| 7.2       | 3-state buffer functions available . . . . .        | 6         |
| 7.3       | 3-state inverter functions available . . . . .      | 7         |
| 7.4       | 3-state multiplexer functions available . . . . .   | 7         |
| 7.5       | 3-state AND/NOR functions available . . . . .       | 8         |
| 7.6       | 3-state NAND/OR functions available . . . . .       | 10        |
| 7.7       | 3-state XOR/XNOR functions available . . . . .      | 12        |
| <b>8</b>  | <b>Limiting values</b> . . . . .                    | <b>14</b> |
| <b>9</b>  | <b>Recommended operating conditions</b> . . . . .   | <b>14</b> |
| <b>10</b> | <b>Static characteristics</b> . . . . .             | <b>15</b> |
| <b>11</b> | <b>Dynamic characteristics</b> . . . . .            | <b>16</b> |
| <b>12</b> | <b>Waveforms</b> . . . . .                          | <b>18</b> |
| <b>13</b> | <b>Transfer characteristics</b> . . . . .           | <b>19</b> |
| <b>14</b> | <b>Waveforms transfer characteristics</b> . . . . . | <b>20</b> |
| <b>15</b> | <b>Package outline</b> . . . . .                    | <b>22</b> |
| <b>16</b> | <b>Abbreviations</b> . . . . .                      | <b>29</b> |
| <b>17</b> | <b>Revision history</b> . . . . .                   | <b>29</b> |
| <b>18</b> | <b>Legal information</b> . . . . .                  | <b>30</b> |
| 18.1      | Data sheet status . . . . .                         | 30        |
| 18.2      | Definitions . . . . .                               | 30        |
| 18.3      | Disclaimers . . . . .                               | 30        |
| 18.4      | Trademarks . . . . .                                | 31        |
| <b>19</b> | <b>Contact information</b> . . . . .                | <b>31</b> |
| <b>20</b> | <b>Contents</b> . . . . .                           | <b>32</b> |

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2013.

All rights reserved.

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

Date of release: 5 April 2013

Document identifier: 74LVC1G99